# RoHS Compliant SATA-Disk Module 6

SDM6-M 7P/180D SP Product Specifications

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Version 1.1



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## **Features:**

- Compliance with SATA Revision 3.1
  - SATA 6.0 Gbps interface
  - Backward compatible with SATA 1.5/3.0 Gbps interfaces
  - ATA command set
- Capacities
  - 16, 32, 64 GB

#### • Performance\*

- Interface burst read/write: 600 MB/sec
- Sustained read: up to 525 MB/sec
- Sustained write: up to 180 MB/sec
- Flash Management
  - Built-in hardware ECC
  - Wear leveling
  - Bad block management
  - S.M.A.R.T.
  - Power Failure Management
  - TRIM
- NAND Flash Type: MLC

- Temperature ranges
  - Operating: Standard: 0°C to 70°C Extended: -40°C to 85°C
  - Storage: -40°C to 100°C
- Supply voltage
  - $-5V \pm 5\%$
- Power consumption (typical)\*
  - Active mode: 350 mA
  - Idle mode: 70 mA
- Form factor
  - Dimensions (30 x 23 x 1.2, unit: mm)
- Connector
  - 7-pin signal connector
  - Power segment in two types: power cable and power cable-less types
- RoHS compliant

\*Varies from capacities. The values addressed here are typical and may vary depending on host system settings.



# **Table of Contents**

I. GENERAL DESCRIPTION	
2. FUNCTIONAL BLOCK	
3. PIN ASSIGNMENTS 4	
4. PRODUCT SPECIFICATION	6
<ul> <li>4.1 CAPACITY</li> <li>4.2 PERFORMANCE</li></ul>	
5. FLASH MANAGEMENT	
<ul> <li>5.1 ERROR CORRECTION/DETECTION</li></ul>	
6. SOFTWARE INTERFACE	
6.1 Command Set 6.2 S.M.A.R.T.	
7. ELECTRICAL SPECIFICATION	
7.1 OPERATING VOLTAGE 7.1 POWER CONSUMPTION 8. MECHANICAL SPECIFICATIONS	
9. PRODUCT ORDERING INFORMATION	



# **1. General Description**

Apacer SDM6-M (SATA Disk Module 6-M) is Apacer next generation disk-on-module (DOM) series that offers elevated speed boost and higher error correction capabilities. Built with SATA 6.0 Gb/s interface, SDM6-M delivers higher performance in data transfer than its previous SDM selections, reaching up to 525 MB/s in read and 180 MB/s in write.

With its SATA interface compliance and compact size, this high-speed disk module defines an ideal balance of performance, capacities, reliability and cost. SDM6-M comes in moderate capacities that are suitable to boot industrial applications and light operating systems for specific operations, while with some extra memory space for data storage. The architectural nature of SATA disk module provides higher resistance to external environmental influences and better flexibility for motherboard space.

Regarding data reliability, SDM6-M is built in with powerful ECC engine that can correct up to 72 bits per 1KB data. In addition, the controller unit of this DOM device supports wear-leveling, SMART and power failure management for data integrity. Wit its trustable reliability, performance and cost effectiveness, Apacer's SDM6-M is definitely the ideal storage or cache solution for embedded and industrial computers, servers and thin clients.

# **2. Functional Block**

SDM6-M includes the SATA and Flash Management controllers, and flash media, as well as the SATA standard interface. Figure 2-1 shows the functional block diagram.

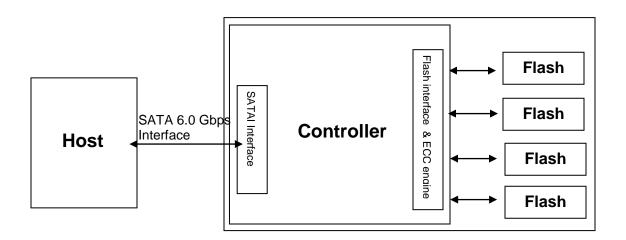
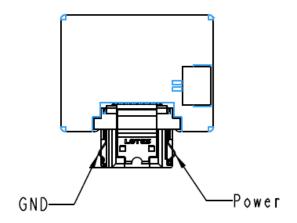


Figure 2-1: Functional block diagram



# **3. Pin Assignments**



#### Table 3-1: Signal segment

Pin	Туре	Description
Pin 1	GND	
Pin 2	RxP	+ Differential Receive Signal
Pin 3	RxN	- Differential Receive Signal
Pin 4	GND	
Pin 5	TxN	- Differential Transmit Signal
Pin 6	TxP	+ Differential Transmit Signal
Pin 7	GND	

Table 3-2: Power segment

Name	Description
Pin 1	VCC (5V)
Pin 2	GND



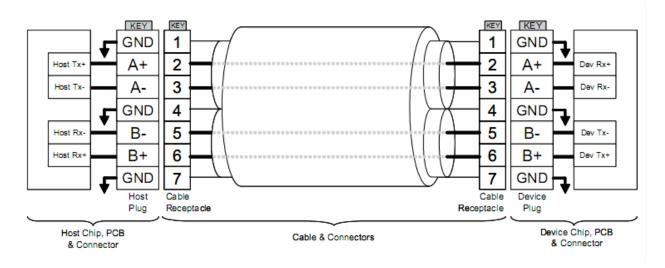


Figure 3-1 SATA Cable/Connector Connection Diagram

The connector on the left represents the Host with TX/RX differential pairs connected to a cable. The connector on the right shows the Device with TX/RX differential pairs also connected to the cable. Notice also the ground path connecting the shielding of the cable to the Cable Receptacle.



# **4. Product Specification**

### 4.1 Capacity

Capacity specification of SDM6-M is available as shown in Table 4-1. It lists the specific capacity and the default numbers of heads, sectors and cylinders for each product line.

Capacity	Total bytes*	Cylinders	Heads	Sectors	Max LBA
16 GB	16,013,942,784	16,383	16	63	31,277,232
32 GB	32,017,047,552	16,383	16	63	62,533,296
64 GB	64,023,257,088	16,383	16	63	125,045,424

Table 4-1: Capacity specification	Table 4-1:
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\*Display of total bytes varies from file systems, which means not all of the bytes can be used for storage.

\*\*Notes: 1 GB = 1,000,000,000 bytes; 1 sector = 512 bytes.

LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the SSD is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.

### 4.2 Performance

Performances of SDM6-M are listed below in table 4-2

Capacity Performance	16 GB	32 GB	64 GB
Sustained Read (MB/s)	320	515	525
Sustained Write (MB/s)	165	175	180

#### Table 4-2: Performance

Note: Performance varies from flash configurations or host system settings.



#### **4.3 Environmental Specifications**

Environmental specification of SDM6-M product family MIL-STD-810 standards is available as shown in Table 4-3.

ltem	Specification
Operating temp.	$0^{\circ}$ C ~70 $^{\circ}$ C (standard) ; -40 $^{\circ}$ C ~85 $^{\circ}$ C (extended)
Non-operating temp.	-40°C∼100°C
Operating vibration	20~2000(Hz), 7.69 (Grms), random wave, X, Y, Z axis
Non-operating vibration	10~2000(Hz), 15(G), sine wave, X, Y, Z axis
Operating shock	50(G), 11(ms), half-sine wave
Non-operating shock	1500(G), 0.5(ms), half-sine wave

#### Table 4-3 SDM6-M environmental specifications

#### 4.4 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in SDM6-M. The prediction result for SDM6-M is more than 1,000,000 hours.

Notes about the MTBF:

The MTBF is predicated and calculated based on "Telcordia Technologies Special Report, SR-332, Issue 2" method.

#### 4.5 Certification and Compliance

SDM6-M complies with the following standards:

- CE
- FCC
- RoHS Recast
- MIL-STD-810



# **5. Flash Management**

#### 5.1 Error Correction/Detection

Flash memory cells will deteriorate with use, which might generate random bit errors in the stored data. Thus, this mSATA SSD module applies the BCH ECC Algorithm, which can detect and correct errors occur during Read process, ensure data been read correctly, as well as protect data from corruption. This device can correct up to 72bit/1K data.

#### 5.2 Bad Block Management

Current production technology is unable to guarantee total reliability of NAND flash memory array. When a flash memory device leaves factory, it comes with a minimal number of initial bad blocks during production or out-of-factory as there is no currently known technology that produce flash chips free of bad blocks. In addition, bad blocks may develop during program/erase cycles. When host performs program/erase command on a block, bad block may appear in Status Register. Since bad blocks are inevitable, the solution is to keep them in control. Apacer flash devices are programmed with ECC, block mapping technique and S.M.A.R.T to reduce invalidity or error. Once bad blocks are detected, data in those blocks will be transferred to free blocks and error will be corrected by designated algorithms.

### 5.3 Wear Leveling

Flash memory devices differ from Hard Disk Drives (HDDs) in terms of how blocks are utilized. For HDDs, when a change is made to stored data, like erase or update, the controller mechanism on HDDs will perform overwrites on blocks. Unlike HDDs, flash blocks cannot be overwritten and each P/E cycle wears down the lifespan of blocks gradually. Repeatedly program/erase cycles performed on the same memory cells will eventually cause some blocks to age faster than others. This would bring flash storages to their end of service term sooner. Wear leveling is an important mechanism that level out the wearing of blocks so that the wearing-down of blocks can be almost evenly distributed. This will increase the lifespan of SSDs. Commonly used wear leveling types are Static and Dynamic.

#### 5.4 Power Failure Management

Power Failure Management plays a crucial role when experiencing unstable power supply. Power disruption may occur when users are storing data into the SSD. In this urgent situation, the controller would run multiple write-to-flash cycles to store the metadata for later block rebuilding. This urgent operation requires about several milliseconds to get it done. At the next power up, the firmware will perform a status tracking to retrieve the mapping table and resume previously programmed NAND blocks to check if there is any incompleteness of transmission.

## 5.5 ATA Secure Erase

ATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.



#### **5.6 TRIM**

TRIM is a SATA command that helps improve the read/write performance and efficiency of solid-state drives (SSD). The command enables the host operating system to inform SSD controller which blocks contain invalid data, mostly because of the erase commands from host. The invalid will be discarded permanently and the SSD will retain more space for itself.



# 6. Software Interface

## 6.1 Command Set

This section defines the software requirements and the format of the commands the host sends to SDM6-M. Commands are issued to SDM6-M by loading the required registers in the command block with the supplied parameters, and then writing the command code to the Command register.

Code	Command	Code	Command
E5h	Check Power Mode	F3h	Security Erase Prepare
06h	Data Set Management	F4h	Security Erase Unit
90h	Execute Device Diagnostic	F5h	Security Freeze Lock
E7h	Flush Cache	F1h	Security Set Password
EAh	Flush Cache EXT	F2h	Security Unlock
Ech	Identify Device	70h	Seek
E3h	Idle	Efh	Set Features
E1h	Idle Immediate	C6h	Set Multiple Mode
91h	Initialize Device Parameters	E6h	Sleep
C8h	Read DMA	B0h	SMART
25h	Read DMA EXT	E2h	Standby
C4h	Read Multiple	E0h	Standby Immediate
29h	Read Multiple EXT	Cah	Write DMA
20h	Read Sector	35h	Write DMA EXT
24h	Read Sector EXT	C5h	Write Multiple
40h	Read Verify Sectors	39h	Write Multiple EXT
42h	Read Verify Sectors EXT	30h	Write Sector
10h	Recalibrate	34h	Write Sector EXT
F6h	Security Disable Password		

Table 6-1: Command set

## 6.2 S.M.A.R.T.

S.M.A.R.T. is an abbreviation for Self-Monitoring, Analysis and Reporting Technology, a self-monitoring system that provides indicators of drive health as well as potential disk problems. It serves as a warning for users from unscheduled downtime by monitoring and displaying critical drive information. Ideally, this should allow taking proactive actions to prevent drive failure and make use of S.M.A.R.T. information for future product development reference.

Apacer devices use the standard SMART command B0h to read data out from the drive to activate our S.M.A.R.T. feature that complies with the ATA/ATAPI specifications. S.M.A.R.T. Attribute IDs shall include initial bad block count, total later bad block count, maximum erase count, average erase count,

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power on hours and power cycle. When the S.M.A.R.T. Utility running on the host, it analyzes and reports the disk status to the host before the device reaches in critical condition.

Note: attribute IDs may vary from product models due to various solution design and supporting capabilities.

Apacer memory products come with S.M.A.R.T. commands and subcommands for users to obtain information of drive status and to predict potential drive failures. Users can take advantage of the following commands/subcommands to monitor the health of the drive.

Code	SMART Subcommand
D0h	READ DATA
D1h	READ ATTRIBUTE THRESHOLDS
D2h	Enable/Disable Attribute Autosave
D4h	Execute Off-line Immediate
D5h	Read Log (optional)
D6h	Write Log (optional)
D8h	Enable Operations
D9h	Disable operations
Dah	Return Status

#### **General SMART attribute structure**

Byte	Description
0	ID (Hex)
1 – 2	Status flag
3	Value
4	Worst
5*-11	Raw Data

\*Byte 5: LSB

#### SMART attribute ID list

ID (Hex)	Attribute Name
9 (0x09)	Power-on hours
12 (0x0C)	Power cycle count
163 (0xA3)	Max. erase count
164 (0xA4)	Avg. erase count
166 (0xA6)	Total later bad block count
167 (0xA7)	SSD Protect Mode (vendor specific)
168 (0xA8)	SATA PHY Error Count
175 (0xAF)	Bad Cluster Table Count
192 (0xC0)	Unexpected Power Loss Count
194 (0xC2)	Temperature
241 (0xF1)	Total sectors of write



# **7. Electrical Specification**

## 7.1 Operating Voltage

Table 7-1 lists the supply voltage for SDM6-M.

Table 7-1 SDM6-M operating voltage

Parameter	Conditions
Supply voltage	5V ±5%

### 7.1 Power Consumption

Table 7-2 lists the power consumption for SDM6-M.

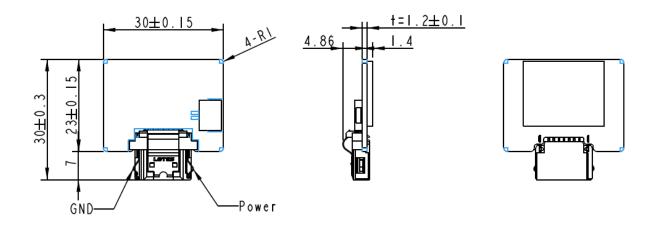
Capacity Modes	16 GB	32 GB	64 GB
Active (mA)	260	320	350
ldle (mA)	70	70	70

 Table 7-2:
 Typical power consumption

Note: Results may differ from various flash configurations or host system setting



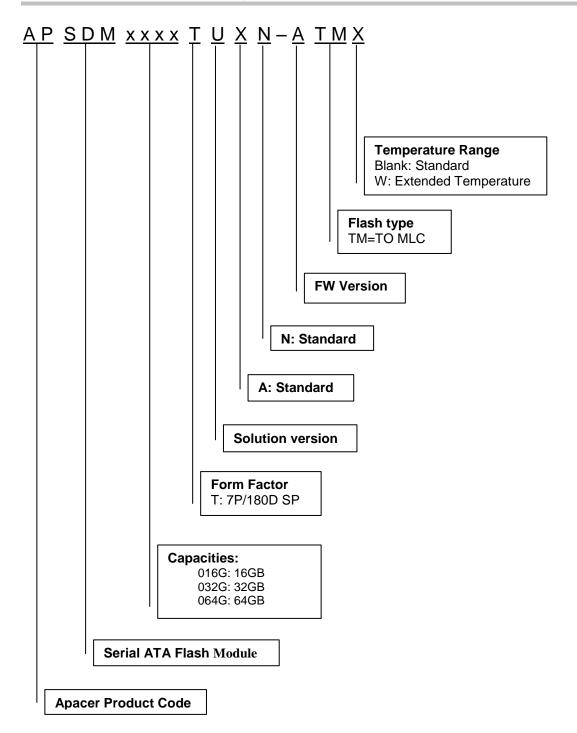
# **8. Mechanical Specifications**





# 9. Product Ordering Information

#### 9.1 Product Code Designations





#### 9.2 Valid Combinations

7P/ 180D SP

Capacity	Standard	Extended Temperature
16GB	APSDM016GTUAN-ATM	APSDM016GTUAN-ATMW
32GB	APSDM032GTUAN-ATM	APSDM032GTUAN-ATMW
64GB	APSDM064GTUAN-ATM	APSDM064GTUAN-ATMW



# **Revision History**

Revision	Date	Description	Remark
1.0	06/16/2015	First release	
1.1	07/06/2015	<ul> <li>Added extended temperature support</li> <li>Revised product ordering information</li> </ul>	



## **Global Presence**

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